

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of:)
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	Toshiki Makimoto, et al.)
)
Serial No.:	10/516,380) Art Unit
) 2818
Filed:	November 30, 2004)
)
Confirmation No.:	2860)
)
For:	P-TYPE NITRIDE SEMICONDUCTOR)
	STRUCTURE AND BIPOLAR TRANSISTOR)
)
Examiner:	Tram Hoang Nguyen)

AUTHORIZATION TO CHARGE DEPOSIT ACCOUNT

Commissioner for Patents
PO Box 1450
Alexandria, Virginia 22313-1450

Sir:

The Commissioner is hereby authorized to charge payment of the following fees associated with this communication or credit any overpayment to Deposit Account No. 23-3178.

X Any additional filing fees required under 37 CFR§1.16.

X Any patent application processing fees under 37 CFR§1.17.

Dated this 23rd day of April 2007.

Respectfully submitted,

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